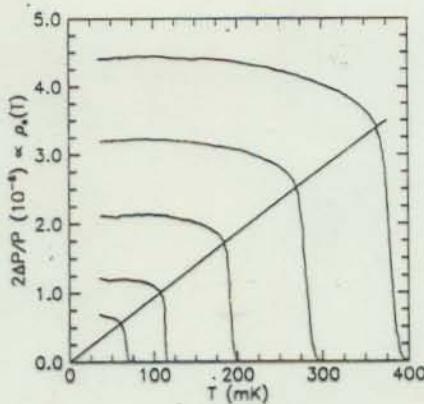


Kosterlitz-Thouless Transition

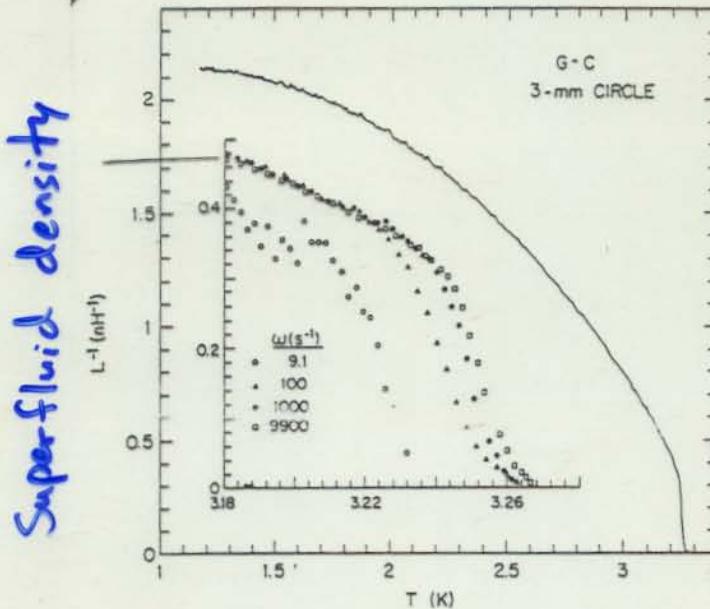
Superfluid density



Superfluid
 ^4He films

G. Agnolet (1989).

FIGURE B.2: Superfluid area density ρ_s of ^4He films of various thickness versus temperature T . The straight line marks the location of the universal jump according to Eq. (B.29). Taken from [6].

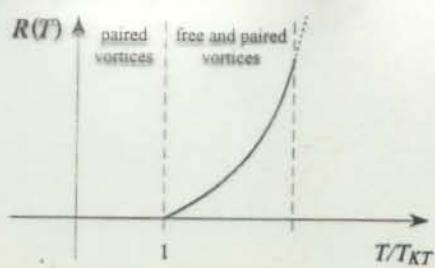


In/InOx
Superconducting
Films

Fisoy + Hebard

FIG. 4. Inverse kinetic inductance vs temperature for circular film sample G-C at $\omega = 10^3 \text{ s}^{-1}$ (solid curve). Inset: dependence near the transition at given frequencies.

$$n_{s=0}^*(T_{KT}) = \frac{2m^*k_B}{\pi\hbar^2} T_{KT}$$



IV Curves at
the Kosterlitz -
Thouless Transition

$V \sim I^{a(\tau)}$

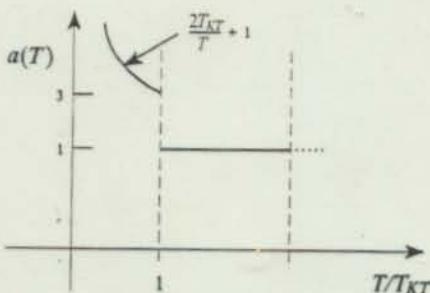


FIG. 23. Schematic drawing of $R(T)$ (the array resistance) and $a(T)$ (the IV exponent) as function of the temperature in the low current limit. $R(T)$ varies with temperature according to Eq. (5.6); $a(T)$ varies according to Eq. (5.18).

2 D
Josephson Junction
Array

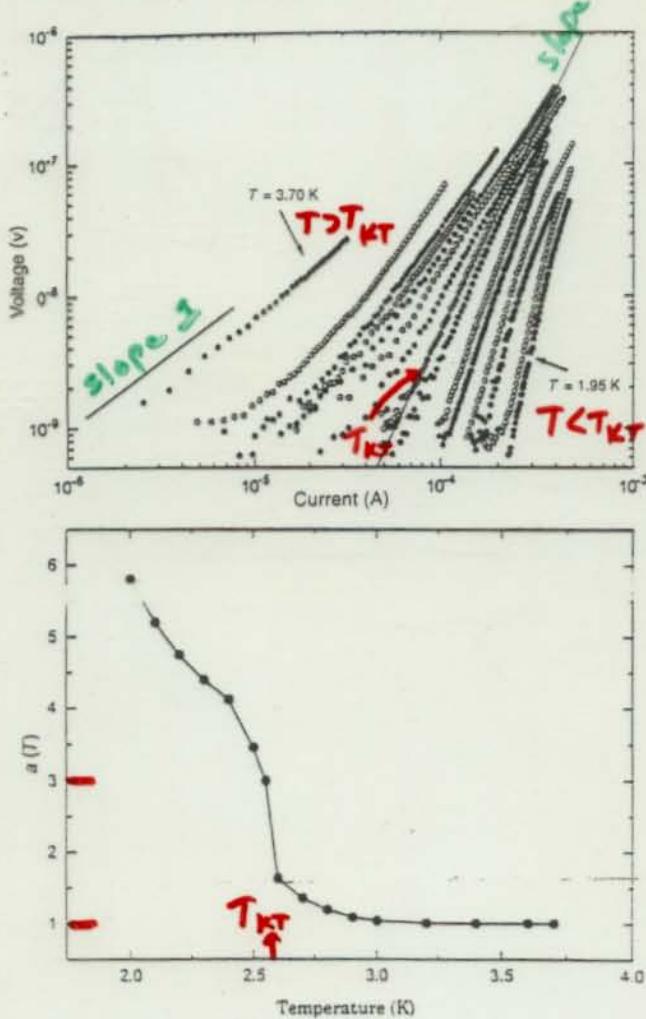


FIG. 24. (a) Current-voltage characteristic curves for a square array of niobium crosses on a gold underlayer (see Fig. 10). (From Ref. 39, Fig. 2(a).) (b) The power-law exponent $a(T)$ versus T for the data in (a).